

SCHOTTKY DIE SPECIFICATION

TYPE: MBR360

General Description: 60 V 3A (Low Ir)

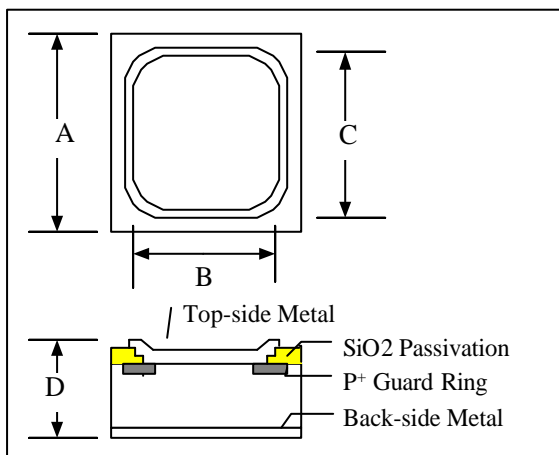
Single Anode

ELECTRICAL CHARACTERISTICS	SYM	Spec. Limit	Die Sort	UNIT
DC Blocking Voltage: Ir=1mA(for wafer form)	VRRM	60	63	Volt
Ir=0.5mA (for dice form)				
Average Rectified Forward Current	IFAV	3		Amp
Maximum Instantaneous Forward Voltage				
@ 3 Amperes, Ta=25°C	VF MAX	0.645	0.635	Volt
Maximum Instantaneous Reverse Voltage				
VR= 60 Volt, Ta=25°C	IR MAX	0.1	0.09	mA
Maximum Junction Capacitance @ 0V, 1MHZ	Cj MAX			pF
MAXIMUM RATINGS				
Nonrepetitive Peak Surge Current	IFSM	100		Amp
Operating Junction Temperature	Tj	-65 to +125		°C
Storage Temperatures	TSTG	-65 to +125		°C

Specification apply to die only. Actual performance may degrade when assembled.

MEMT does not guarantee device performance after assembly.

Data sheet information is subjected to change without notice.

DICE OUTLINE DRAWING


DIM	ITEM	um ²	Mil ²
A	Die Size	1524	60.00
B	Top Metal Pad Size	1424	56.1
C	Passivation Seal	1444	56.9
D	Thickness (Min)	254	10
	Thickness (Max)	305	12

PS:

(1)Cutting street width is around 80um(3.14mil).

(2)Both of top-side and back-side metals are Ti/Ni/Ag